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- EPIC™ (Enhanced-Performance Implanted CMOS) 2-µ Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC}, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 > 2 V at V_{CC}, T_A = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JEDEC Standard JESD-17
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Ceramic (J) 300-mil DIPs

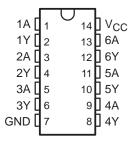
description

These hex inverters are designed for 2.7-V to $5.5\text{-V}\ \text{V}_{CC}$ operation.

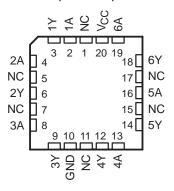
The 'LVU04 contain six independent inverters with unbuffered outputs. These devices perform the Boolean function $Y = \overline{A}$.

The SN74LVU04 is available in Tl's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

SN54LVU04 . . . J OR W PACKAGE SN74LVU04 . . . D, DB, OR PW PACKAGE (TOP VIEW)



SN54LVU04 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

The SN54LVU04 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74LVU04 is characterized for operation from -40° C to 85°C.

FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	L
L	Н



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

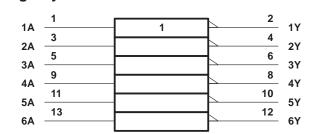
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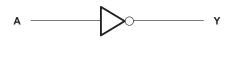


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logic symbol†

logic diagram, each inverter (positive logic)





Pin numbers shown are for D, DB, J, PW and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, VO (see Notes 1 and 2)	. -0.5 V to $V_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Maximum power dissipation at $T_A = 55^{\circ}$ C (in still air) (see Note 3): D package	1.25 W
DB or PW packag	ge 0.5 W
Storage temperature range, T _{stq}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stressratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 7 V maximum.
 - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

recommended operating conditions (see Note 4)

			SN54L	SN54LVU04		SN74LVU04	
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2.7	5.5	2.7	5.5	V
V		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.4		2.4		V
VIH	V _{IH} High-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	3.55		3.55		V
V _{II} Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.5		0.5	V	
VIL	VIL LOW-level input voitage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.8		0.8	V
٧ _I	Input voltage		0.4	Vcc	0	VCC	V
۷o	Output voltage		0	Vcc	0	Vcc	V
la	High level output ourrent	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	200	-6		-6	mA
ЮН	High-level output current	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	Q.	-12		-12	mA
la.	Low lovel output ourset	V _{CC} = 2.7 V to 3.6 V		6		6	A
IOL FO	_ow-level output current V _{CC} = 4.5 V to 5.5 V			12		12	mA
Δt/Δν	Input transition rise or fall rate		0	100	0	100	ns/V
T _A Operating free-air temperature			-55	125	-40	85	°C
	Operating free-air temperature		-55	125	-40	85	L

NOTE 4: Unused inputs must be held high or low to prevent them from floating.



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		v _{cc} †	SN	54LVU0	4	SN	4	UNIT	
PARAMETER	lesi co	TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	ONI
VOH	VI = VIL,	I _{OH} = -100 μA	MIN to MAX	V _{CC} -0.	5		V _{CC} -0.	5		
	V _I = GND,	$I_{OH} = -6 \text{ mA}$	3 V	2.4			2.4			V
	V _I = GND,	$I_{OH} = -12 \text{ mA}$	4.5 V	3.6			3.6			
VOL	VI = VIH,	$I_{OL} = 100 \mu\text{A}$	MIN to MAX			0.5			0.5	
	$V_I = V_{CC}$	$I_{OL} = 6 \text{ mA}$	3 V		14	0.4			0.4	V
	$V_I = V_{CC}$	$I_{OL} = 12 \text{ mA}$	4.5 V		KI	0.55			0.55	
1.	V. Var or CND		3.6 V		,0	±1			±1	
li li	$V_I = V_{CC}$ or GND	5.5 V		Ć)	±1			±1	μΑ	
laa	Vi – Voe er CND	$I_{O} = V_{CC}$ or GND, $I_{O} = 0$	3.6 V	100		20			20	
lcc	AL = ACC OLGIND		5.5 V	Q'		20			20	μΑ
ΔICC	One input at V _{CC} – Other inputs at V _{CC}		3 V to 3.6 V			500			500	μΑ
C.	Vi – Voe or CND	V V CND	3.3 V		7			7		pF
C _i	V _I = V _{CC} or GND	5 V		7.5			7.5		pΓ	

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

			SN54LVU04							
PARAMETER	FROM (INPUT)	TO V _{CC} = 5 V ± 0.5 V		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 2.7 \text{ V}$		$V \pm 0.5 \text{ V}$ V _{CC} = 3.3 V ± 0.3 V			2.7 V	UNIT
	(1141 01)	(0011 01)	MIN	TYP MAX	MIN	TYP	MAX	MIN	MAX	
^t pd	А	Υ		5 10		8	13	RE	13	ns

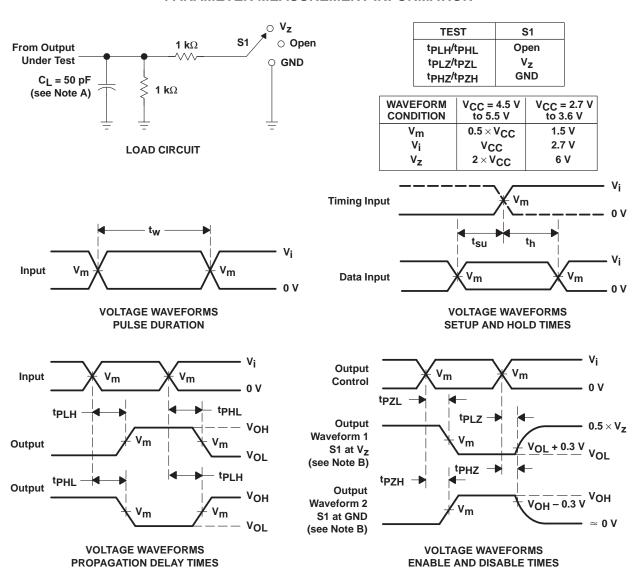
switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER						SN74L	.VU04				
	FROM TO (OUTPUT)	TO (OUTPUT)	V_{CC} = 5 V \pm 0.5 V		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$			0.3 V	VCC =	2.7 V	UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	MAX		
^t pd	А	Y		5	10		8	13		13	ns

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	VCC	TYP	UNIT
C _{pd}	Power dissipation capacitance per inverter	C _I = 50 pF, f = 10 MHz	3.3 V	7	pF
	Power dissipation capacitance per inverter	C _L = 30 pr,	5 V	12	l pr

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.

LOW- AND HIGH-LEVEL ENABLING

- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.

INVERTING AND NONINVERTING OUTPUTS

- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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